


### STANDARD DIODES

### NEWADD-A-pak™ Power Modules

#### Features

- Electrically isolated: DBC base plate
- 3500 V<sub>RMS</sub> isolating voltage
- Standard JEDEC package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Wide choice of circuit configurations
- Large creepage distances
- UL E78996 approved 

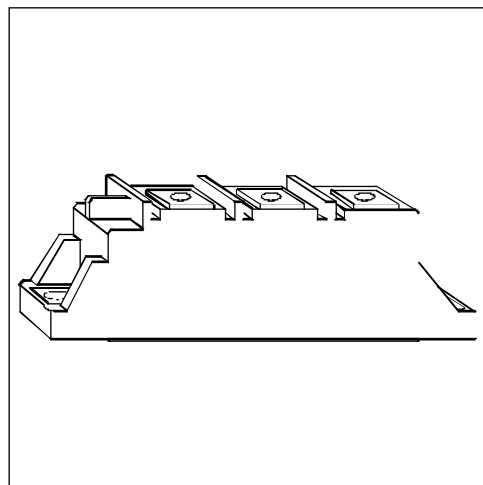
100 A

#### Description

These IRK series of NEW ADD-A-paks use power diodes in a variety of circuit configurations. The semiconductor chips are electrically isolated from the base plate, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges. These modules are intended for general purpose high voltage applications such as battery chargers, welders and plating equipment

#### Major Ratings and Characteristics

Parameters	IRK.91	Units
$I_{F(AV)}$	100	A
@ $T_C$	100	°C
$I_{F(RMS)}$	157	A
$I_{FSM}$ @ 50Hz	2020	A
@ 60Hz	2110	A
$I^2t$ @ 50Hz	20.43	KA <sup>2</sup> s
@ 60Hz	18.65	KA <sup>2</sup> s
$I^2\sqrt{t}$	204.3	KA <sup>2</sup> √s
$V_{RRM}$ range	400 to 1600	V
$T_J$	-40 to 150	°C
$T_{STG}$	-40 to 150	°C



## IRK.91 Series

Bulletin I27141 rev. C 09/97

International  
 Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{RRM}$ , maximum repetitive peak reverse voltage V	$V_{RSM}$ , maximum non-repetitive peak rev. voltage V	$I_{RRM}$ max. @ $T_J = 150^\circ\text{C}$ mA
IRK.91	04	400	500	10
	06	600	700	
	08	800	900	
	10	1000	1100	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

#### Forward Conduction

Parameter	IRK.91	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	100	A	180° conduction, half sine wave
	100	°C	
$I_{F(AV)}$ Max. average forward current @ Case temperature	90	A	180° conduction, half sine wave
	107	°C	
$I_{F(RMS)}$ Max. RMS forward current	157	A	DC @ 90°C case temperature
$I_{FSM}$ Max. peak, one-cycle forward, non-repetitive surge current	2020	A	t = 10ms No voltage
	2110		t = 8.3ms reapplied
	1700		t = 10ms 100% $V_{RRM}$
	1780		t = 8.3ms reapplied
$I^2t$ Maximum $I^2t$ for fusing	20.43	KA <sup>2</sup> s	t = 10ms No voltage
	18.65		t = 8.3ms reapplied
	14.45		t = 10ms 100% $V_{RRM}$
	13.19		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	204.3	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.79	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ max.
$V_{F(TO)2}$ High level value of threshold voltage	0.87		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ max.
$r_{f1}$ Low level value of forward slope resistance	1.78	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ max.
$r_{f2}$ High level value of forward slope resistance	1.57		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ max.
$V_{FM}$ Max. forward voltage drop	1.45	V	$I_{FM} = \pi \times I_{F(AV)}$ , $T_J = 25^\circ\text{C}$ , $t_p = 400\mu\text{s}$ square wave

#### Blocking

Parameter	IRK.91	Units	Conditions
$I_{RRM}$ Max. peak reverse leakage current	10	mA	$T_J = 150^\circ\text{C}$
$V_{INS}$ RMS isolation voltage	3500 (1 sec)	V	50 Hz, circuit to base, all terminals shorted

**Thermal and Mechanical Specifications**

Parameter	IRK.91	Units	Conditions
T <sub>J</sub> Max. junction operating temperature range	-40 to 150	°C	
T <sub>stg</sub> Storage temperature range	-40 to 150		
R <sub>thJC</sub> Max. thermal resistance, junction to case	0.35	K/W	Per junction, DC operation
R <sub>thCS</sub> Typical thermal resistance, case to heatsink	0.1		Mounting surface flat, smooth and greased Flatness < 0.03 mm; roughness < 0.02 mm
T Mounting torque ±10%	to heatsink	5	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound
	busbar	4	
wt Approximate weight	83 (3)	g (oz)	
Case style	TO-240AA	JEDEC	

**ΔR Conduction (per Junction)**

(The following table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC)

Devices	Sine half wave conduction					Rect. wave conduction					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.91	0.052	0.064	0.082	0.112	0.164	0.043	0.069	0.088	0.115	0.165	°C/W

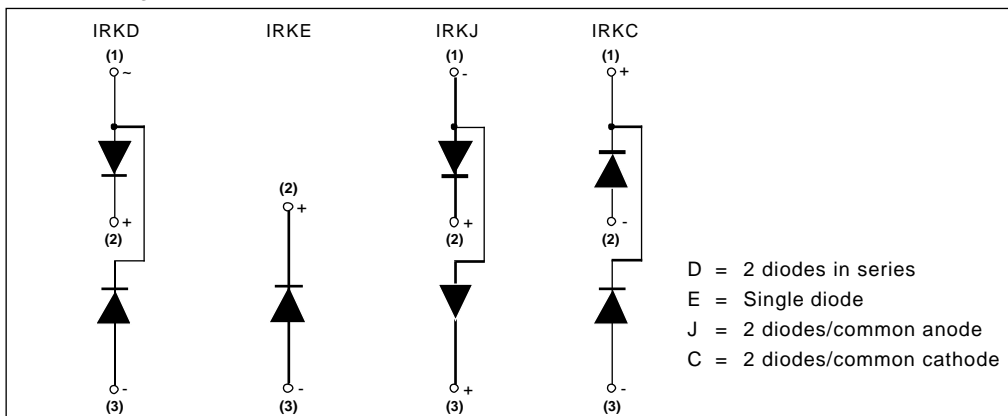
**Ordering Information Table**

**Device Code**

IRK	D	91	/	16
①	②	③		④

- 1 - Module type
- 2 - Circuit configuration (See Circuit Configuration Table)
- 3 - Current code
- 4 - Voltage code (See Voltage Ratings Table)

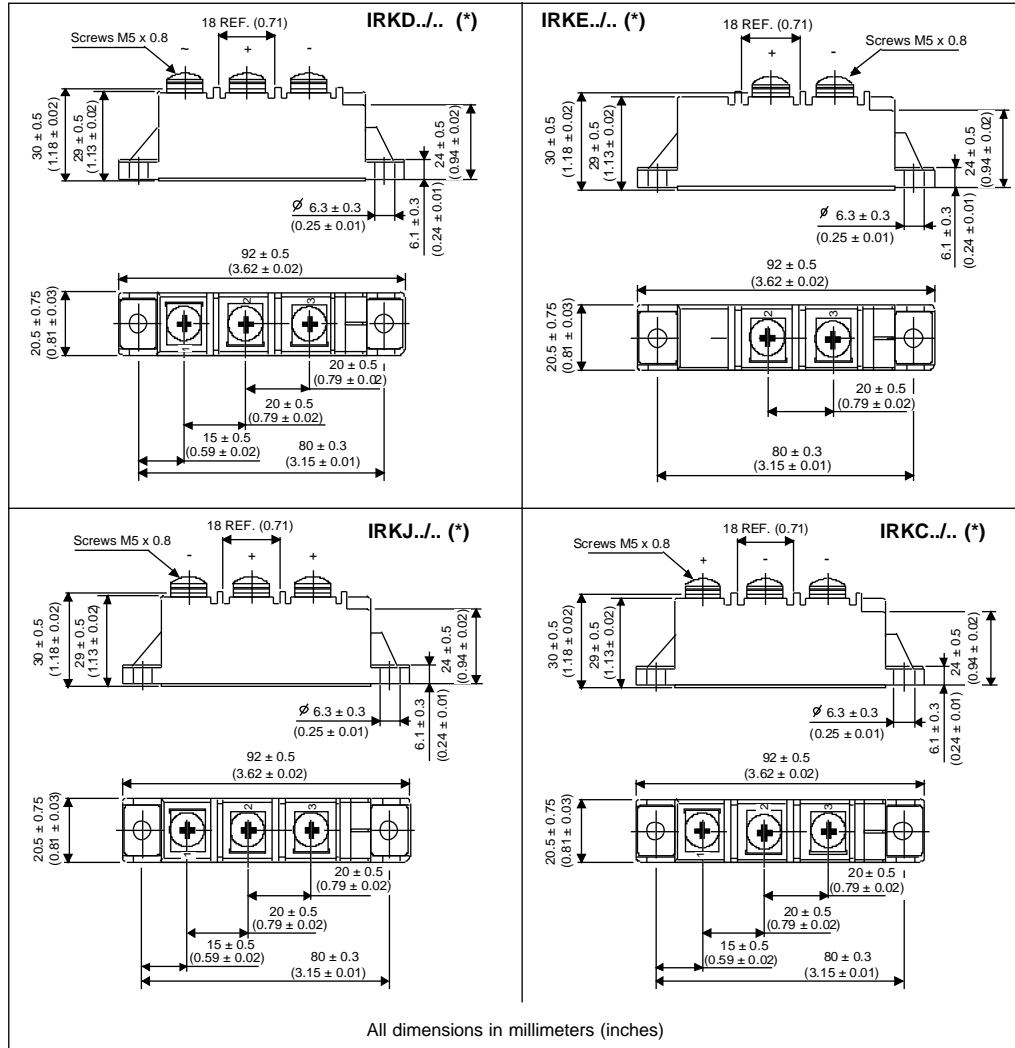
**Circuit Configurations Table**



**IRK.91 Series**

Bulletin I27141 rev. C 09/97

**Outlines Table**



(\*) For terminals connections, see Circuit Configurations Table

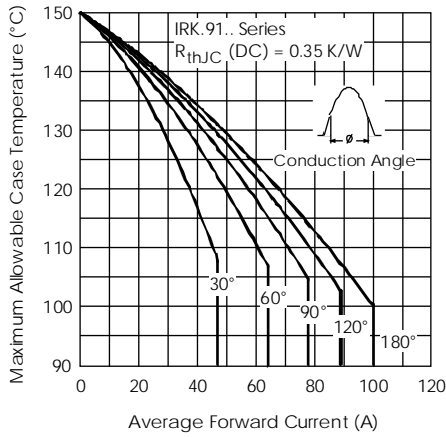


Fig. 1 - Current Ratings Characteristics

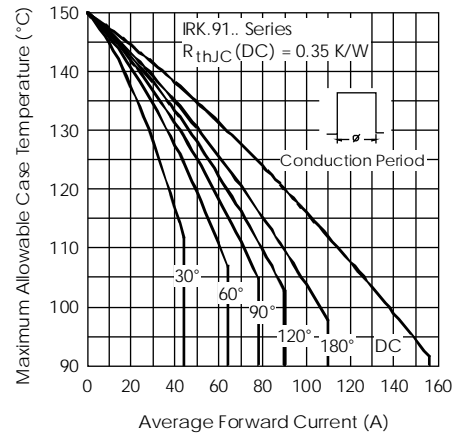


Fig. 2 - Current Ratings Characteristics

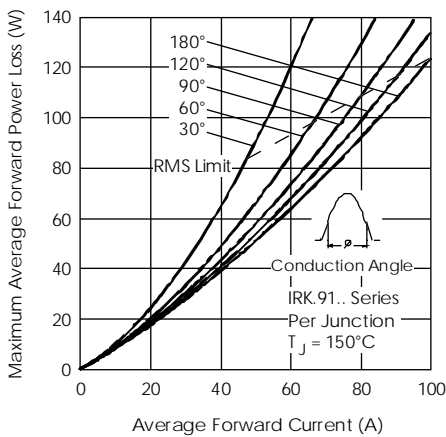


Fig. 3 - Forward Power Loss Characteristics

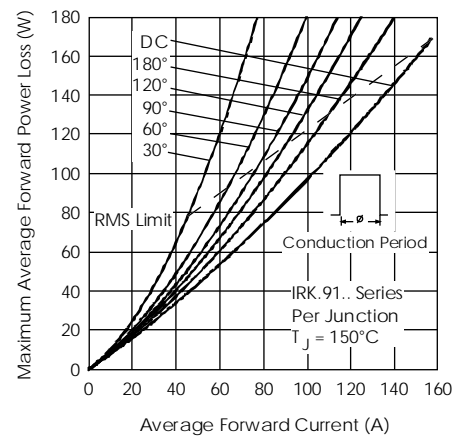


Fig. 4 - Forward Power Loss Characteristics

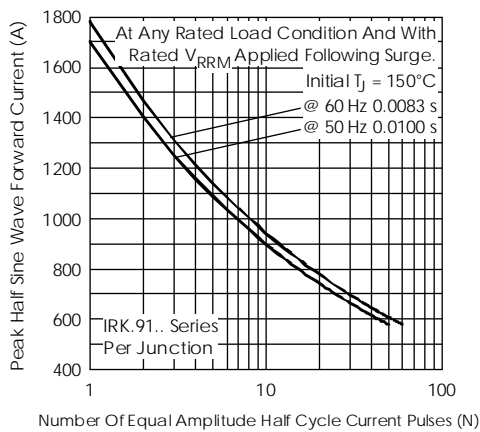


Fig. 5 - Maximum Non-Repetitive Surge Current

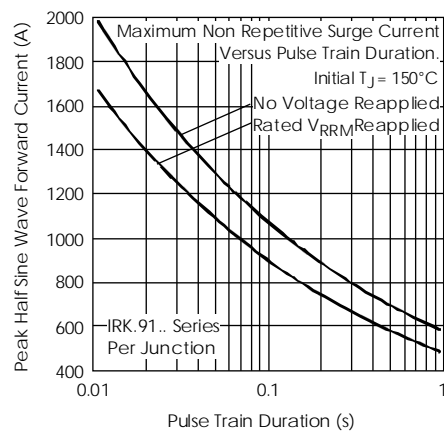


Fig. 6 - Maximum Non-Repetitive Surge Current

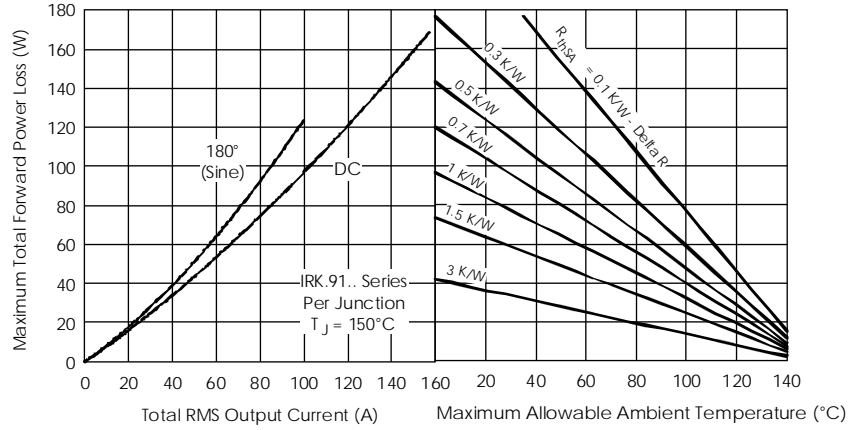


Fig. 7 - Forward Power Loss Characteristics

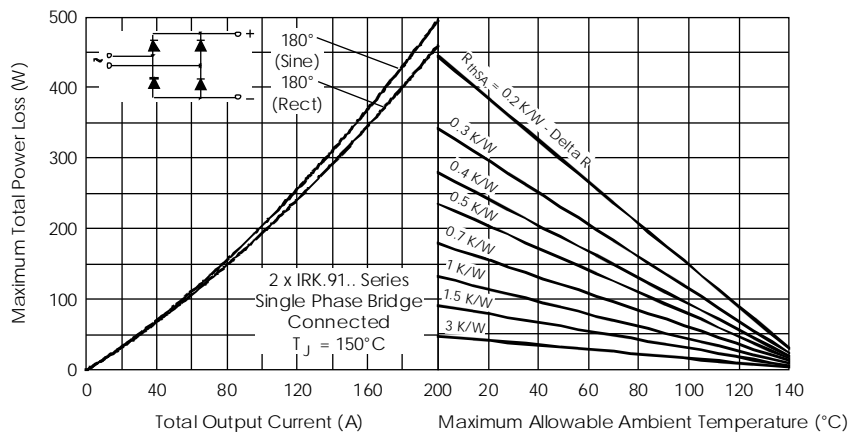


Fig. 8 - Forward Power Loss Characteristics

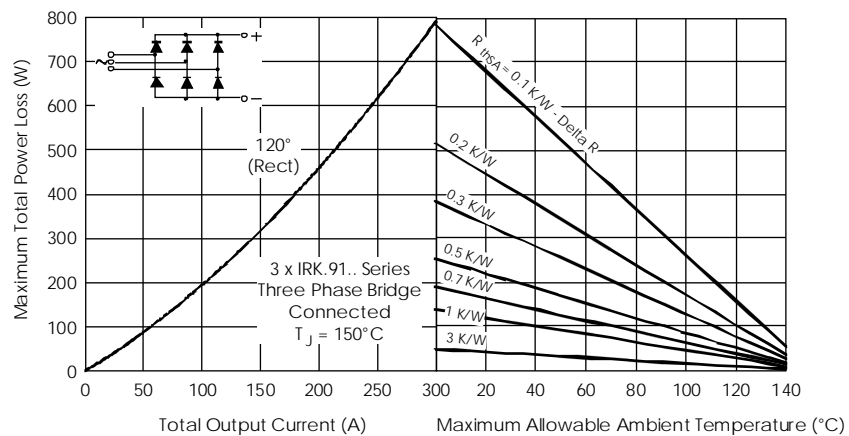


Fig. 9 - Forward Power Loss Characteristics

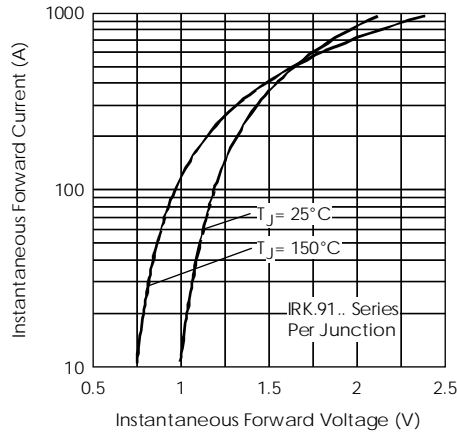


Fig. 10 - Forward Voltage Drop Characteristics

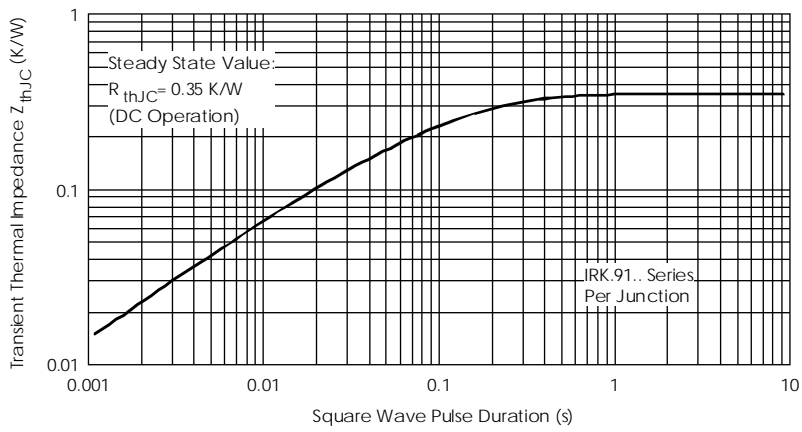


Fig. 11 - Thermal Impedance  $Z_{thJC}$  Characteristic